具有可配置电压转换、三态输出和总线保持输入的 SN74AXCH1T45 1 位双电源总线收发器

1 特性

- 完全可配置的双电源轨设计可允许各个端口在 0.65V 至 3.6V 的电源电压范围内运行
- 工作温度：–40°C 至 +125°C
- 无干扰电源定序
- 总线保持数据输入消除了对外部上拉或下拉电阻的需求
- 最大静态电流 (I_{CCA} + I_{CCB}) 为 10μA（最高 85°C）和 16μA（最高 125°C）
- 从 1.8V 转换到 3.3 V 时，支持高达 500Mbps 的转换速率
- V_{CC} 隔离特性
  - 如果任何一个 V_{CC} 输入低于 100mV，则所有 I/O 输出均禁用且处于高阻抗状态
- I_{off} 支持局部关断模式运行
- 闩锁性能超过 100mA，符合 JESD 78 II 类规范的要求
- ESD 保护性能超过 JESD 22 规范要求
  - 8000V 人体放电模型
  - 1000V 充电器件模型

2 应用

- 个人电子产品
- 企业与通信
- 无线基础设施
- 楼宇自动化
- 电子销售终端
- 企业级固态硬盘

3 说明

SN74AXCH1T45 是一款采用两个独立可配置电源轨的单比特位同相总线收发器。V_{CCA} 和 V_{CCB} 电源电压低至 0.65V 时，该器件可正常工作。A 端口用于跟踪 V_{CCA}，该端口可支持 0.65V 至 3.6V 范围内的任何电源电压。B 端口用于跟踪 V_{CCB}，该端口也可支持 0.65V 至 3.6V 范围内的任何电源电压。此外，SN74AXCH1T45 还与单电源系统兼容。

DIR 引脚决定信号传播的方向。DIR 引脚配置为高电平时，信号转换由端口 A 流向端口 B。DIR 配置为低电平时，则由端口 B 流向端口 A。DIR 引脚以 V_{CCA} 为基准，这意味着它的逻辑高电平和逻辑低电平阈值跟踪 V_{CCA} 电压。

有源总线保持电路会将未使用或未驱动的输入保持在有效逻辑状态。不建议在总线保持电路上使用上拉或下拉电阻器。如果 V_{CCA} 或 V_{CCB} 连上电源，则总线保持电路分别在 A 端口或 B 端口上始终保持工作状态，与方向控制引脚的状态无关。

该器件完全符合使用 I_{off} 电流的部分断电应用的规范要求。当器件断电时，I_{off} 保护电路可确保不从输入、输出或偏置到特定电压的组合 I/O 获取多余电流，也不向其提供多余电流。

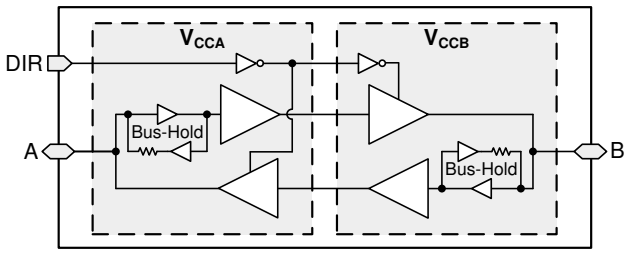
V_{CC} 隔离特性可确保当 V_{CCA} 或 V_{CCB} 低于 100mV 时，I/O 端口均禁用其输出并进入高阻态。

无干扰电源时序使电源轨能以任何顺序打开或关断，从而提供强大的电源时序性能。

器件信息

器件型号	封装(1)	封装尺寸（标称值）
SN74AXCH1T45DBV	SOT-23 (6)	2.90mm × 1.60mm
SN74AXCH1T45DCK	SC70 (6)	2.00mm × 1.25mm
SN74AXCH1T45DTQ	X2SON (6)	1.00mm x 0.80mm
SN74AXCH1T45DRY	SON (6)	1.40mm x 1.00mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。



功能方框图

本文档旨在为方便起见，提供有关 TI 产品中文版本的信息，以确认产品的概要。有关适用的官方英文版本的最新信息，请访问 www.ti.com，其内容始终优先。TI 不保证翻译的准确性和有效性。在实际设计之前，请务必参考最新版本的英文版本。

Table of Contents

1 特性 1
2 应用 1
3 说明 1
4 Revision History 2
5 Pin Configuration and Functions 3
6 Specifications 4
6.1 Absolute Maximum Ratings 4
6.2 ESD Ratings 4
6.3 Recommended Operating Conditions 5
6.4 Thermal Information 5
6.5 Electrical Characteristics 6
6.6 Operating Characteristics: T_A = 25°C 13
6.7 Typical Characteristics 14
7 Parameter Measurement Information 16
7.1 Load Circuit and Voltage Waveforms 16
8 Detailed Description 18
8.1 Overview 18
8.2 Functional Block Diagram 18
8.3 Feature Description 18
8.4 Device Functional Modes 20
9 Application and Implementation 21
9.1 Application Information 21
9.2 Typical Applications 21
10 Power Supply Recommendations 24
11 Layout 24
11.1 Layout Guidelines 24
11.2 Layout Example 24
12 Device and Documentation Support 25
12.1 Documentation Support 25
12.2 接收文档更新通知 25
12.3 支持资源 25
12.4 Trademarks 25
12.5 静电放电警告 25
12.6 术语表 25
13 Mechanical, Packaging, and Orderable Information 26

4 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision B (June 2020) to Revision C (September 2020) — **Page**

- Updated I_{CCA}, I_{CCB}, and I_{CCA} + I_{CCB} to reflect updated performance of device 6

Changes from Revision A (January 2019) to Revision B (June 2020) — **Page**

- 向*器件信息*表添加了 DRY 封装选项 1
- Added pinout drawing for DRY package 3

Changes from Revision * (December 2018) to Revision A (January 2019) — **Page**

- 向*器件信息*表添加了 DBV 和 DTQ 封装选项 1
- 更新了*修订历史记录*部分 1
- Added pinout drawings for DBV and DTQ packages 3
- Added DRY package to Pin Configurations 3

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5 Pin Configuration and Functions

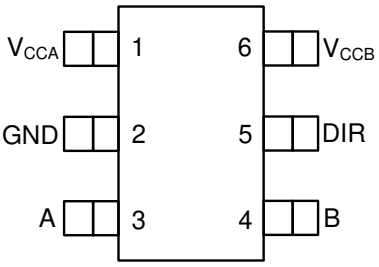

图 5-1. DBV Package 6-Pin SOT-23 Top View

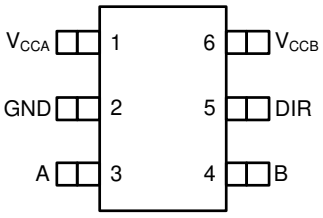

图 5-2. DCK Package 6-Pin SC70 Top View

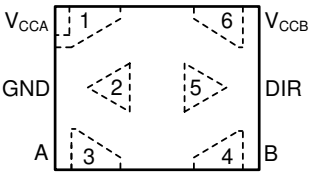

图 5-3. DTQ Package 6-Pin X2SON Transparent Top View

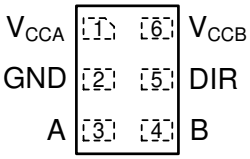

图 5-4. DRY Package 6-Pin SON Transparent Top View

Pin Functions

PIN		TYPE	DESCRIPTION
NO.	NAME		
1	V_{CCA}	—	A-port supply voltage. 0.65 V ≤ V_{CCA} ≤ 3.6 V.
2	GND	—	Ground
3	A	I/O	Input/output A. This pin is referenced to V_{CCA}.
4	B	I/O	Input/output B. This pin is referenced to V_{CCB}.
5	DIR	I	Direction control signal. See for functionality.
6	V_{CCB}	—	B-port supply voltage. 0.65 V ≤ V_{CCB} ≤ 3.6 V.

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CCA}	Supply voltage A		– 0.5	4.2	V
V_{CCB}	Supply voltage B		– 0.5	4.2	V
V_I	Input Voltage(2)	I/O Ports (A Port)	– 0.5	4.2	V
		I/O Ports (B Port)	– 0.5	4.2	
		Control Inputs	– 0.5	4.2	
V_O	Voltage applied to any output in the high-impedance or power-off state(2)	A Port	– 0.5	4.2	V
		B Port	– 0.5	4.2	
V_O	Voltage applied to any output in the high or low state(2) (3)	A Port	– 0.5	V_{CCA} + 0.2	V
		B Port	– 0.5	V_{CCB} + 0.2	
I_{IK}	Input clamp current	V_I < 0	– 50		mA
I_{OK}	Output clamp current	V_O < 0	– 50		mA
I_O	Continuous output current		– 50	50	mA
	Continuous current through V_{CC} or GND		– 100	100	mA
T_j	Junction Temperature			150	°C
T_{stg}	Storage temperature		– 65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
(3) The output positive-voltage rating may be exceeded up to 4.2 V maximum if the output current rating is observed.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±8000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101(2)	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

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6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1) (2) (3)

				MIN	MAX	UNIT
V_{CCA}	Supply voltage A			0.65	3.6	V
V_{CCB}	Supply voltage B			0.65	3.6	V
V_{IH}	High-level input voltage	Data Inputs	V_{CCI} = 0.65 V - 0.75 V	V_{CCI} x 0.70		V
			V_{CCI} = 0.76 V - 1 V	V_{CCI} x 0.70		
			V_{CCI} = 1.1 V - 1.95 V	V_{CCI} x 0.65		
			V_{CCI} = 2.3 V - 2.7 V	1.6		
			V_{CCI} = 3 V - 3.6 V	2		
		Control Input (DIR) Referenced to V_{CCA}	V_{CCA} = 0.65 V - 0.75 V	V_{CCA} x 0.70		
			V_{CCA} = 0.76 V - 1 V	V_{CCA} x 0.70		
			V_{CCA} = 1.1 V - 1.95 V	V_{CCA} x 0.65		
			V_{CCA} = 2.3 V - 2.7 V	1.6		
			V_{CCA} = 3 V - 3.6 V	2		
V_{IL}	Low-level input voltage	Data Inputs	V_{CCI} = 0.65 V - 0.75 V		V_{CCI} x 0.30	V
			V_{CCI} = 0.76 V - 1 V		V_{CCI} x 0.30	
			V_{CCI} = 1.1 V - 1.95 V		V_{CCI} x 0.35	
			V_{CCI} = 2.3 V - 2.7 V		0.7	
			V_{CCI} = 3 V - 3.6 V		0.8	
		Control Input (DIR) Referenced to V_{CCA}	V_{CCA} = 0.65 V - 0.75 V		V_{CCA} x 0.30	
			V_{CCA} = 0.76 V - 1 V		V_{CCA} x 0.30	
			V_{CCA} = 1.1 V - 1.95 V		V_{CCA} x 0.35	
			V_{CCA} = 2.3 V - 2.7 V		0.7	
			V_{CCA} = 3 V - 3.6 V		0.8	
V_I	Input voltage (3)			0	3.6	V
V_O	Output voltage	Active State		0	V_{CCO}	V
		Tri-State		0	3.6	
$\Delta t/\Delta v$	Input transition rate				100	ns/V
T_A	Operating free-air temperature			–40	125	°C

(1) VCCI is the VCC associated with the input port.
(2) VCCO is the VCC associated with the output port.
(3) All unused inputs of the device must be held at VCC or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs.

6.4 Thermal Information

THERMAL METRIC(1)		SN74AXCH1T45				UNIT
		DBV (SOT-23)	DCK (SC70)	DTQ (X2SON)	DRY (SON)	
		6 PINS	6 PINS	6 PINS	6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	214.0	223.9	327.8	308.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	151.8	150.9	194.9	206.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	93.6	75.3	248.4	181.7	°C/W
ψ_{JT}	Junction-to-top characterization parameter	78.1	58.2	24.1	42.6	°C/W
ψ_{JB}	Junction-to-board characterization parameter	93.4	75.0	247.6	180.8	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, SPRA953.

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6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted) (1) (2)

PARAMETER		TEST CONDITIONS		V_{CCA}	V_{CCB}	Operating free-air temperature (T_A)						UNIT
						– 40°C to 85°C			– 40°C to 125°C			
						MIN	TYP(3)	MAX	MIN	TYP	MAX	
V_{OH}	High-level output voltage	$V_I = V_{IH}$	I_{OH} = – 100 µA	0.7 V - 3.6 V	0.7 V - 3.6 V	V_{CCO} – 0.1			V_{CCO} – 0.1			V
			I_{OH} = – 50 µA	0.65 V	0.65 V	0.55			0.55			
			I_{OH} = – 200 µA	0.76 V	0.76 V	0.58			0.58			
			I_{OH} = – 500 µA	0.85 V	0.85 V	0.65			0.65			
			I_{OH} = – 3 mA	1.1 V	1.1 V	0.85			0.85			
			I_{OH} = – 6 mA	1.4 V	1.4 V	1.05			1.05			
			I_{OH} = – 8 mA	1.65 V	1.65 V	1.2			1.2			
			I_{OH} = – 9 mA	2.3 V	2.3 V	1.75			1.75			
			I_{OH} = – 12 mA	3 V	3 V	2.3			2.3			
V_{OL}	Low-level output voltage	$V_I = V_{IL}$	I_{OL} = 100 µA	0.7 V - 3.6 V	0.7 V - 3.6 V			0.1			0.1	V
			I_{OL} = 50 µA	0.65 V	0.65 V			0.1			0.1	
			I_{OL} = 200 µA	0.76 V	0.76 V			0.18			0.18	
			I_{OL} = 500 µA	0.85 V	0.85 V			0.2			0.2	
			I_{OL} = 3 mA	1.1 V	1.1 V			0.25			0.25	
			I_{OL} = 6 mA	1.4 V	1.4 V			0.35			0.35	
			I_{OL} = 8 mA	1.65 V	1.65 V			0.45			0.45	
			I_{OL} = 9 mA	2.3 V	2.3 V			0.55			0.55	
			I_{OL} = 12 mA	3 V	3 V			0.7			0.7	
I_{BHL}	Bus-hold low sustaining current (4)	V_I = 0.20 V		0.65 V	0.65 V	4			4			µA
		V_I = 0.23 V		0.76 V	0.76 V	8			7			
		V_I = 0.26 V		0.85 V	0.85 V	10			10			
		V_I = 0.39 V		1.1 V	1.1 V	20			20			
		V_I = 0.49 V		1.4 V	1.4 V	40			30			
		V_I = 0.58 V		1.65 V	1.65 V	55			45			
		V_I = 0.7 V		2.3 V	2.3 V	90			80			
		V_I = 0.8 V		3 V	3 V	145			135			
I_{BHH}	Bus-hold high sustaining current (5)	V_I = 0.45 V		0.65 V	0.65 V	– 4			– 4			µA
		V_I = 0.53 V		0.76 V	0.76 V	– 8			– 7			
		V_I = 0.59 V		0.85 V	0.85 V	– 10			– 10			
		V_I = 0.71 V		1.1 V	1.1 V	– 20			– 20			
		V_I = 0.91 V		1.4 V	1.4 V	– 40			– 30			
		V_I = 1.07 V		1.65 V	1.65 V	– 55			– 45			
		V_I = 1.6 V		2.3 V	2.3 V	– 90			– 80			
		V_I = 2.0 V		3 V	3 V	– 145			– 135			

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6.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted) (1) (2)

PARAMETER		TEST CONDITIONS		V_{CCA}	V_{CCB}	Operating free-air temperature (T_A)						UNIT
						−40°C to 85°C			−40°C to 125°C			
						MIN	TYP(3)	MAX	MIN	TYP	MAX	
I_{BHLO}	Bus-hold low overdrive current (6)	V_I = 0 to V_{CC}		0.75 V	0.75 V	40			40			µA
				0.84 V	0.84 V	50			50			
				0.95 V	0.95 V	65			65			
				1.3 V	1.3 V	105			105			
				1.6 V	1.6 V	150			150			
				1.95 V	1.95 V	205			205			
				2.7 V	2.7 V	335			335			
				3.6 V	3.6 V	480			480			
I_{BHHO}	Bus-hold high overdrive current (7)	V_I = 0 to V_{CC}		0.75 V	0.75 V	−40			−40			µA
				0.84 V	0.84 V	−50			−50			
				0.95 V	0.95 V	−65			−65			
				1.3 V	1.3 V	−105			−105			
				1.6 V	1.6 V	−150			−150			
				1.95 V	1.95 V	−205			−205			
				2.7 V	2.7 V	−335			−335			
				3.6 V	3.6 V	−480			−480			
I_I	Input leakage current	Control input (DIR): V_I = V_{CCA} or GND		0.65 V - 3.6 V	0.65 V - 3.6 V	−0.5		0.5	−1		1	µA
		A or B Port: Vi = V_{CCI} or GND		0.65 V - 3.6 V	0.65 V - 3.6 V	−4		4	−8		8	
I_{off}	Partial power down current	A or B Port: Vi or Vo = 0 V - 3.6 V		0 V	0 V - 3.6 V	−8		8	−12		12	µA
				0 V - 3.6 V	0 V	−8		8	−12		12	
I_{CCA}	V_{CCA} supply current	V_I = V_{CCI} or GND	I_O = 0	0.65 V - 3.6 V	0.65 V - 3.6 V			8			12	µA
				0 V	3.6 V	−2			−8			
				3.6 V	0 V			2			8	
I_{CCB}	V_{CCB} supply current	V_I = V_{CCI} or GND	I_O = 0	0.65 V - 3.6 V	0.65 V - 3.6 V			8			12	µA
				0 V	3.6 V			2			8	
				3.6 V	0 V	−2			−8			
I_{CCA} + I_{CCB}	Combined supply current	V_I = V_{CCI} or GND	I_O = 0	0.65 V - 3.6 V	0.65 V - 3.6 V			10			16	µA
C_i	Control input capacitance	V_I = 3.3 V or GND		3.3 V	3.3 V		4.3			4.3		pF
C_{io}	Data I/O capacitance, A Port	V_O = 1.65 V DC +1 MHz -16 dBm sine wave		3.3 V	0 V		7.4			7.4		pF
C_{io}	Data I/O capacitance, B Port	V_O = 1.65 V DC +1 MHz -16 dBm sine wave		0 V	3.3 V		7.4			7.4		pF

(1) VCCI is the VCC associated with the input port.
(2) VCCO is the VCC associated with the output port.
(3) All typical data is taken at 25°C.
(4) The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL}(MAX). I_{BHL} should be measured after lowering V_I to GND and then raising it to V_{IL}(MAX).
(5) The bus-hold circuit can source at least the minimum high sustaining current at V_{IH}(MIN). I_{BHH} should be measured after raising V_I to V_{CC} and then lowering it to V_{IH}(MIN).
(6) An external driver must source at least I_{BHLO} to switch this node from low to high.

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(7) An external driver must sink at least I_{BHHO} to switch this node from high to low.

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表 6-1. Switching Characteristics, V_{CCA} = 0.7 V

t_{pd}	Propagation delay	A	B	–40°C to 85°C	0.5	181	0.5	119	0.5	85	0.5	51	0.5	49	0.5	52	0.5	65	0.5	152	ns
				–40°C to 125°C	0.5	181	0.5	119	0.5	85	0.5	51	0.5	49	0.5	52	0.5	65	0.5	152	
		B	A	–40°C to 85°C	0.5	181	0.5	162	0.5	136	0.5	96	0.5	91	0.5	89	0.5	88	0.5	88	
				–40°C to 125°C	0.5	181	0.5	162	0.5	136	0.5	96	0.5	91	0.5	89	0.5	88	0.5	88	
t_{dis}	Disable time	DIR	A	–40°C to 85°C	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	ns
				–40°C to 125°C	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	
		DIR	B	–40°C to 85°C	0.5	170	0.5	127	0.5	102	0.5	48	0.5	42	0.5	46	0.5	58	0.5	108	
				–40°C to 125°C	0.5	170	0.5	127	0.5	102	0.5	48	0.5	42	0.5	46	0.5	58	0.5	108	
t_{en}	Enable time	DIR	A	–40°C to 85°C	0.5	343	0.5	278	0.5	231	0.5	141	0.5	132	0.5	134	0.5	144	0.5	193	ns
				–40°C to 125°C	0.5	343	0.5	278	0.5	231	0.5	141	0.5	132	0.5	134	0.5	144	0.5	193	
		DIR	B	–40°C to 85°C	0.5	326	0.5	257	0.5	222	0.5	194	0.5	191	0.5	191	0.5	197	0.5	277	
				–40°C to 125°C	0.5	326	0.5	257	0.5	222	0.5	194	0.5	191	0.5	191	0.5	197	0.5	277	

表 6-2. Switching Characteristics, V_{CCA} = 0.8 V

t_{pd}	Propagation delay	A	B	–40°C to 85°C	0.5	162	0.5	98	0.5	65	0.5	33	0.5	28	0.5	26	0.5	27	0.5	37	ns
				–40°C to 125°C	0.5	162	0.5	98	0.5	65	0.5	33	0.5	28	0.5	26	0.5	27	0.5	37	
		B	A	–40°C to 85°C	0.5	119	0.5	98	0.5	81	0.5	54	0.5	45	0.5	44	0.5	43	0.5	42	
				–40°C to 125°C	0.5	119	0.5	98	0.5	81	0.5	54	0.5	45	0.5	44	0.5	43	0.5	42	
t_{dis}	Disable time	DIR	A	–40°C to 85°C	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	ns
				–40°C to 125°C	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	
		DIR	B	–40°C to 85°C	0.5	160	0.5	117	0.5	90	0.5	39	0.5	31	0.5	29	0.5	29	0.5	37	
				–40°C to 125°C	0.5	160	0.5	117	0.5	90	0.5	39	0.5	31	0.5	29	0.5	29	0.5	37	
t_{en}	Enable time	DIR	A	–40°C to 85°C	0.5	268	0.5	205	0.5	165	0.5	90	0.5	74	0.5	71	0.5	70	0.5	77	ns
				–40°C to 125°C	0.5	268	0.5	205	0.5	165	0.5	90	0.5	74	0.5	71	0.5	70	0.5	77	
		DIR	B	–40°C to 85°C	0.5	257	0.5	194	0.5	161	0.5	130	0.5	125	0.5	126	0.5	125	0.5	132	
				–40°C to 125°C	0.5	257	0.5	194	0.5	161	0.5	130	0.5	125	0.5	126	0.5	125	0.5	132	

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表 6-3. Switching Characteristics, V_{CCA} = 0.9 V

t_{pd}	Propagation delay	A	B	–40°C to 85°C	0.5	135	0.5	81	0.5	54	0.5	24	0.5	18	0.5	17	0.5	15	0.5	18	ns
				–40°C to 125°C	0.5	135	0.5	81	0.5	54	0.5	24	0.5	18	0.5	17	0.5	15	0.5	18	
		B	A	–40°C to 85°C	0.5	86	0.5	65	0.5	54	0.5	41	0.5	30	0.5	26	0.5	23	0.5	23	
				–40°C to 125°C	0.5	86	0.5	65	0.5	54	0.5	41	0.5	30	0.5	26	0.5	23	0.5	23	
t_{dis}	Disable time	DIR	A	–40°C to 85°C	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	ns
				–40°C to 125°C	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	
		DIR	B	–40°C to 85°C	0.5	154	0.5	111	0.5	85	0.5	34	0.5	27	0.5	25	0.5	21	0.5	23	
				–40°C to 125°C	0.5	154	0.5	111	0.5	85	0.5	34	0.5	27	0.5	25	0.5	21	0.5	23	
t_{en}	Enable time	DIR	A	–40°C to 85°C	0.5	227	0.5	166	0.5	131	0.5	71	0.5	53	0.5	48	0.5	42	0.5	44	ns
				–40°C to 125°C	0.5	227	0.5	166	0.5	131	0.5	71	0.5	53	0.5	48	0.5	42	0.5	44	
		DIR	B	–40°C to 85°C	0.5	206	0.5	152	0.5	125	0.5	96	0.5	91	0.5	89	0.5	89	0.5	92	
				–40°C to 125°C	0.5	206	0.5	152	0.5	125	0.5	96	0.5	91	0.5	89	0.5	89	0.5	92	

表 6-4. Switching Characteristics, V_{CCA} = 1.2 V

t_{pd}	Propagation delay	A	B	–40°C to 85°C	0.5	95	0.5	54	0.5	41	0.5	16	0.5	11	0.5	9	0.5	8	0.5	8	ns
				–40°C to 125°C	0.5	95	0.5	54	0.5	41	0.5	16	0.5	11	0.5	9	0.5	8	0.5	8	
		B	A	–40°C to 85°C	0.5	51	0.5	33	0.5	24	0.5	16	0.5	13	0.5	11	0.5	8	0.5	8	
				–40°C to 125°C	0.5	51	0.5	33	0.5	24	0.5	16	0.5	13	0.5	11	0.5	8	0.5	8	
t_{dis}	Disable time	DIR	A	–40°C to 85°C	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	ns
				–40°C to 125°C	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	
		DIR	B	–40°C to 85°C	0.5	148	0.5	105	0.5	78	0.5	30	0.5	23	0.5	20	0.5	16	0.5	16	
				–40°C to 125°C	0.5	148	0.5	105	0.5	78	0.5	30	0.5	23	0.5	20	0.5	16	0.5	16	
t_{en}	Enable time	DIR	A	–40°C to 85°C	0.5	191	0.5	129	0.5	96	0.5	43	0.5	34	0.5	30	0.5	23	0.5	22	ns
				–40°C to 125°C	0.5	191	0.5	129	0.5	96	0.5	43	0.5	34	0.5	30	0.5	23	0.5	22	
		DIR	B	–40°C to 85°C	0.5	116	0.5	75	0.5	61	0.5	41	0.5	37	0.5	36	0.5	35	0.5	35	
				–40°C to 125°C	0.5	116	0.5	75	0.5	61	0.5	41	0.5	37	0.5	36	0.5	35	0.5	35	

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表 6-5. Switching Characteristics, V_{CCA} = 1.5 V

t_{pd}	Propagation delay	A	B	–40°C to 85°C	0.5	91	0.5	45	0.5	30	0.5	13	0.5	9	0.5	8	0.5	6	0.5	6	ns
				–40°C to 125°C	0.5	91	0.5	45	0.5	30	0.5	13	0.5	9	0.5	8	0.5	6	0.5	6	
		B	A	–40°C to 85°C	0.5	49	0.5	28	0.5	18	0.5	11	0.5	9	0.5	8	0.5	6	0.5	5	
				–40°C to 125°C	0.5	49	0.5	28	0.5	18	0.5	11	0.5	9	0.5	8	0.5	6	0.5	5	
t_{dis}	Disable time	DIR	A	–40°C to 85°C	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20	ns
				–40°C to 125°C	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20	
		DIR	B	–40°C to 85°C	0.5	146	0.5	103	0.5	76	0.5	28	0.5	21	0.5	19	0.5	15	0.5	14	
				–40°C to 125°C	0.5	146	0.5	103	0.5	76	0.5	28	0.5	21	0.5	19	0.5	15	0.5	14	
t_{en}	Enable time	DIR	A	–40°C to 85°C	0.5	186	0.5	124	0.5	89	0.5	38	0.5	29	0.5	26	0.5	20	0.5	18	ns
				–40°C to 125°C	0.5	186	0.5	124	0.5	89	0.5	38	0.5	29	0.5	26	0.5	20	0.5	18	
		DIR	B	–40°C to 85°C	0.5	104	0.5	58	0.5	43	0.5	31	0.5	28	0.5	27	0.5	25	0.5	25	
				–40°C to 125°C	0.5	104	0.5	58	0.5	43	0.5	31	0.5	28	0.5	27	0.5	25	0.5	25	

表 6-6. Switching Characteristics, V_{CCA} = 1.8 V

t_{pd}	Propagation delay	A	B	–40°C to 85°C	0.5	89	0.5	44	0.5	26	0.5	11	0.5	8	0.5	7	0.5	6	0.5	5	ns
				–40°C to 125°C	0.5	89	0.5	44	0.5	26	0.5	11	0.5	8	0.5	7	0.5	6	0.5	5	
		B	A	–40°C to 85°C	0.5	52	0.5	26	0.5	17	0.5	9	0.5	8	0.5	7	0.5	6	0.5	5	
				–40°C to 125°C	0.5	52	0.5	26	0.5	17	0.5	9	0.5	8	0.5	7	0.5	6	0.5	5	
t_{dis}	Disable time	DIR	A	–40°C to 85°C	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17	ns
				–40°C to 125°C	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17	
		DIR	B	–40°C to 85°C	0.5	147	0.5	103	0.5	76	0.5	27	0.5	20	0.5	18	0.5	14	0.5	13	
				–40°C to 125°C	0.5	147	0.5	103	0.5	76	0.5	27	0.5	20	0.5	18	0.5	14	0.5	13	
t_{en}	Enable time	DIR	A	–40°C to 85°C	0.5	185	0.5	122	0.5	86	0.5	35	0.5	27	0.5	24	0.5	19	0.5	17	ns
				–40°C to 125°C	0.5	185	0.5	122	0.5	86	0.5	35	0.5	27	0.5	24	0.5	19	0.5	17	
		DIR	B	–40°C to 85°C	0.5	100	0.5	54	0.5	37	0.5	27	0.5	25	0.5	24	0.5	22	0.5	22	
				–40°C to 125°C	0.5	100	0.5	54	0.5	37	0.5	27	0.5	25	0.5	24	0.5	22	0.5	22	

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表 6-7. Switching Characteristics, V_{CCA} = 2.5 V

t_{pd}	Propagation delay	A	B	–40°C to 85°C	0.5	88	0.5	42	0.5	23	0.5	8	0.5	6	0.5	6	0.5	5	0.5	5	ns
				–40°C to 125°C	0.5	88	0.5	42	0.5	23	0.5	8	0.5	6	0.5	6	0.5	5	0.5	5	
		B	A	–40°C to 85°C	0.5	65	0.5	27	0.5	15	0.5	8	0.5	6	0.5	6	0.5	5	0.5	4	
				–40°C to 125°C	0.5	65	0.5	27	0.5	15	0.5	8	0.5	6	0.5	6	0.5	5	0.5	4	
t_{dis}	Disable time	DIR	A	–40°C to 85°C	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	ns
				–40°C to 125°C	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	
		DIR	B	–40°C to 85°C	0.5	146	0.5	102	0.5	75	0.5	27	0.5	19	0.5	17	0.5	13	0.5	12	
				–40°C to 125°C	0.5	146	0.5	102	0.5	75	0.5	27	0.5	19	0.5	17	0.5	13	0.5	12	
t_{en}	Enable time	DIR	A	–40°C to 85°C	0.5	191	0.5	122	0.5	85	0.5	33	0.5	25	0.5	22	0.5	17	0.5	16	ns
				–40°C to 125°C	0.5	191	0.5	122	0.5	85	0.5	33	0.5	25	0.5	22	0.5	17	0.5	16	
		DIR	B	–40°C to 85°C	0.5	95	0.5	50	0.5	31	0.5	20	0.5	18	0.5	17	0.5	17	0.5	17	
				–40°C to 125°C	0.5	95	0.5	50	0.5	31	0.5	20	0.5	18	0.5	17	0.5	17	0.5	17	

表 6-8. Switching Characteristics, V_{CCA} = 3.3 V

t_{pd}	Propagation delay	A	B	–40°C to 85°C	0.5	87	0.5	42	0.5	23	0.5	8	0.5	5	0.5	5	0.5	4	0.5	4	ns
				–40°C to 125°C	0.5	87	0.5	42	0.5	23	0.5	8	0.5	5	0.5	5	0.5	4	0.5	4	
		B	A	–40°C to 85°C	0.5	154	0.5	37	0.5	18	0.5	8	0.5	6	0.5	5	0.5	5	0.5	4	
				–40°C to 125°C	0.5	154	0.5	37	0.5	18	0.5	8	0.5	6	0.5	5	0.5	5	0.5	4	
t_{dis}	Disable time	DIR	A	–40°C to 85°C	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	ns
				–40°C to 125°C	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	
		DIR	B	–40°C to 85°C	0.5	147	0.5	102	0.5	75	0.5	26	0.5	19	0.5	17	0.5	13	0.5	12	
				–40°C to 125°C	0.5	147	0.5	102	0.5	75	0.5	26	0.5	19	0.5	17	0.5	13	0.5	12	
t_{en}	Enable time	DIR	A	–40°C to 85°C	0.5	275	0.5	129	0.5	88	0.5	34	0.5	24	0.5	21	0.5	17	0.5	16	ns
				–40°C to 125°C	0.5	275	0.5	129	0.5	88	0.5	34	0.5	24	0.5	21	0.5	17	0.5	16	
		DIR	B	–40°C to 85°C	0.5	94	0.5	49	0.5	30	0.5	18	0.5	16	0.5	16	0.5	15	0.5	15	
				–40°C to 125°C	0.5	94	0.5	49	0.5	30	0.5	18	0.5	16	0.5	16	0.5	15	0.5	15	

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6.6 Operating Characteristics: T_A = 25°C

PARAMETER		TEST CONDITIONS	V_{CCA}	V_{CCB}	MIN	TYP	MAX	UNIT
C_{pdA}	Power Dissipation Capacitance per transceiver (A to B: outputs enabled)	CL = 0, RL = Open f = 1 MHz, tr = tf = 1 ns	0.7 V	0.7 V		2.0		pF
			0.8 V	0.8 V		2.0		
			0.9 V	0.9 V		2.0		
			1.2 V	1.2 V		2.0		
			1.5 V	1.5 V		1.9		
			1.8 V	1.8 V		2.0		
			2.5 V	2.5 V		2.4		
			3.3 V	3.3 V		3.0		
	Power Dissipation Capacitance per transceiver (B to A: outputs enabled)	CL = 0, RL = Open f = 1 MHz, tr = tf = 1 ns	0.7 V	0.7 V		12		pF
			0.8 V	0.8 V		12		
			0.9 V	0.9 V		12		
			1.2 V	1.2 V		12		
			1.5 V	1.5 V		13		
			1.8 V	1.8 V		13		
			2.5 V	2.5 V		17		
			3.3 V	3.3 V		21		
C_{pdB}	Power Dissipation Capacitance per transceiver (A to B: outputs enabled)	CL = 0, RL = Open f = 1 MHz, tr = tf = 1 ns	0.7 V	0.7 V		12		pF
			0.8 V	0.8 V		12		
			0.9 V	0.9 V		12		
			1.2 V	1.2 V		12		
			1.5 V	1.5 V		13		
			1.8 V	1.8 V		13		
			2.5 V	2.5 V		17		
			3.3 V	3.3 V		21		
	Power Dissipation Capacitance per transceiver (B to A: outputs enabled)	CL = 0, RL = Open f = 1 MHz, tr = tf = 1 ns	0.7 V	0.7 V		2.1		pF
			0.8 V	0.8 V		2.2		
			0.9 V	0.9 V		2.2		
			1.2 V	1.2 V		2.2		
			1.5 V	1.5 V		2.3		
			1.8 V	1.8 V		2.3		
			2.5 V	2.5 V		2.6		
			3.3 V	3.3 V		3.3		

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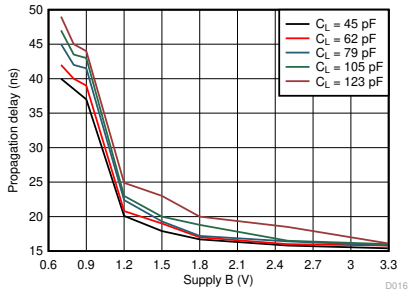
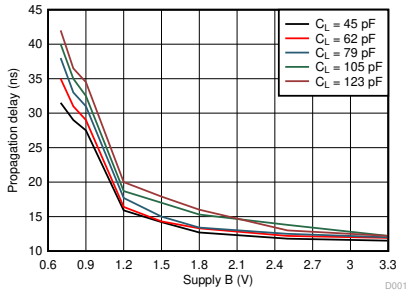
6.7 Typical Characteristics



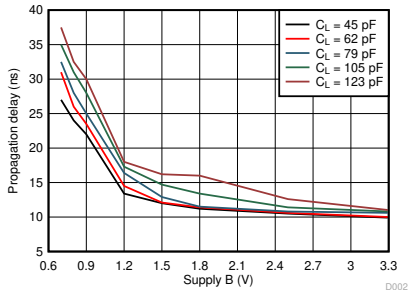
T_A = 25°C V_{CCA} = 0.7 V

图 6-1. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



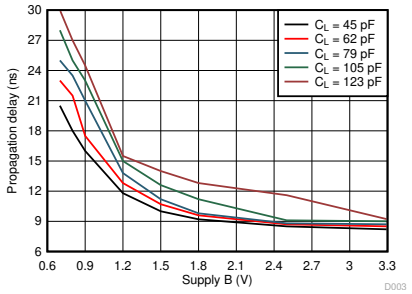
T_A = 25°C V_{CCA} = 0.8 V

图 6-2. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



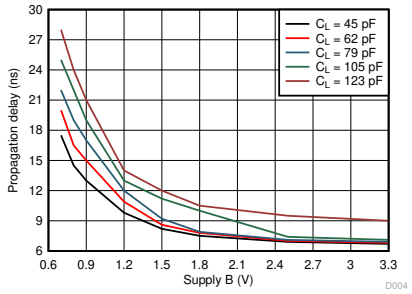
T_A = 25°C V_{CCA} = 0.9 V

图 6-3. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



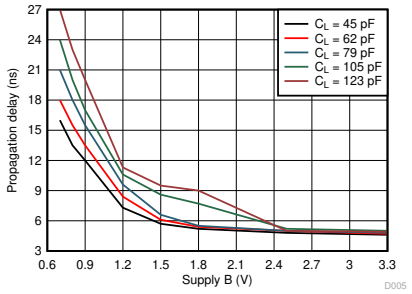
T_A = 25°C V_{CCA} = 1.2 V

图 6-4. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



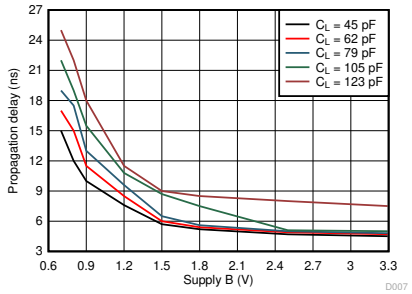
T_A = 25°C V_{CCA} = 1.5 V

图 6-5. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



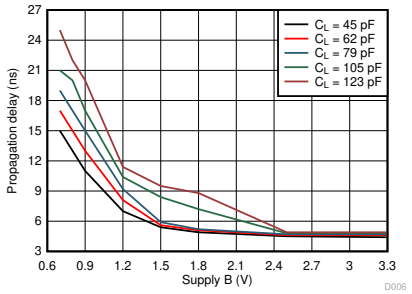
T_A = 25°C V_{CCA} = 1.8 V

图 6-6. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



T_A = 25°C V_{CCA} = 3.3 V

图 6-7. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



T_A = 25°C V_{CCA} = 2.5 V

图 6-8. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance

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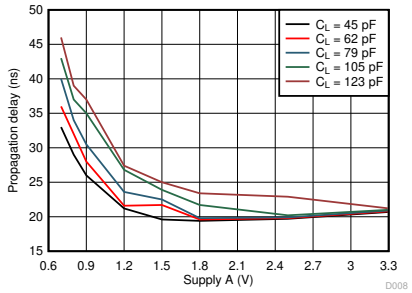
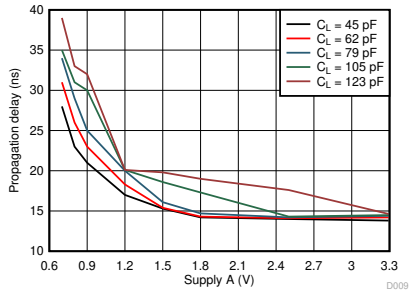


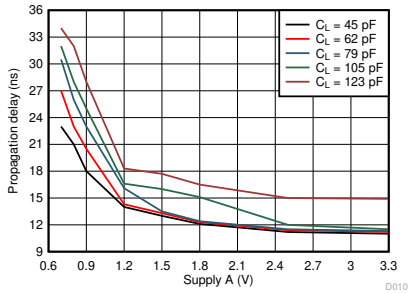
T_A = 25°C V_{CCA} = 0.7 V

图 6-9. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance



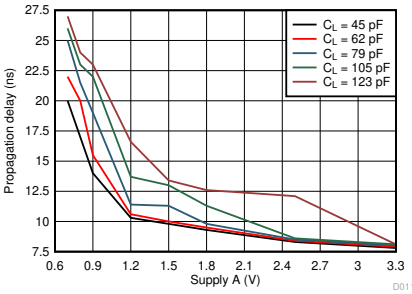
T_A = 25°C V_{CCA} = 0.8 V

图 6-10. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance



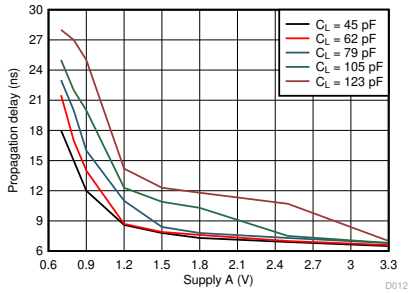
T_A = 25°C V_{CCA} = 0.9 V

图 6-11. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance



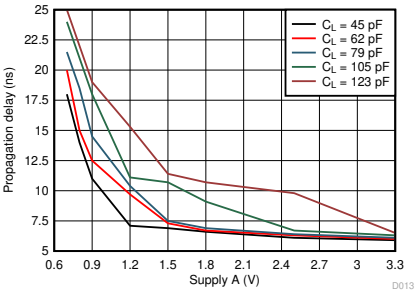
T_A = 25°C V_{CCA} = 1.2 V

图 6-12. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance



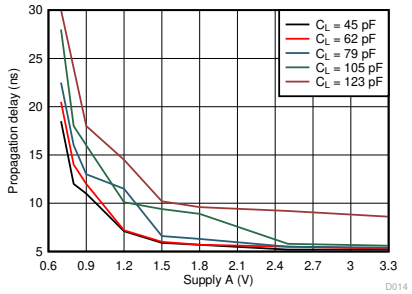
T_A = 25°C V_{CCA} = 1.5 V

图 6-13. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance



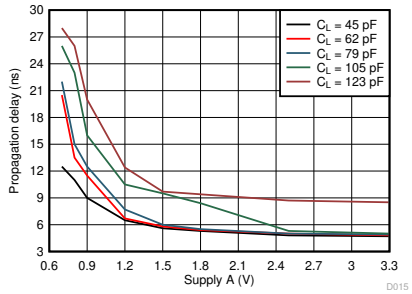
T_A = 25°C V_{CCA} = 1.8 V

图 6-14. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance



T_A = 25°C V_{CCA} = 2.5 V

图 6-15. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance



T_A = 25°C V_{CCA} = 3.3 V

图 6-16. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance

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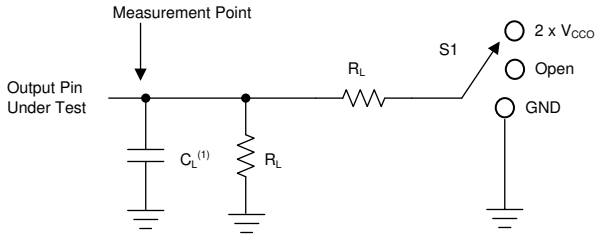
7 Parameter Measurement Information

7.1 Load Circuit and Voltage Waveforms

Unless otherwise noted, all input pulses are supplied by generators having the following characteristics:

- f = 1 MHz
- Z_O = 50 Ω
- dv/dt ≤ 1 ns/V

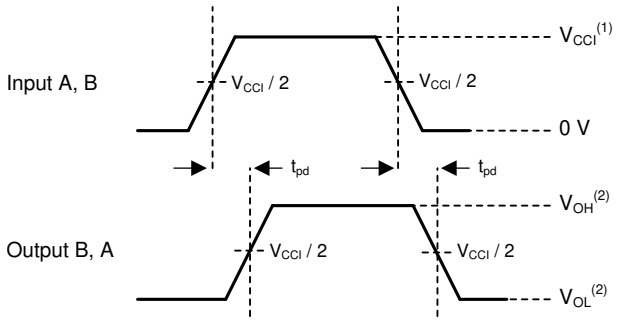


A. C_L includes probe and jig capacitance.

图 7-1. Load Circuit

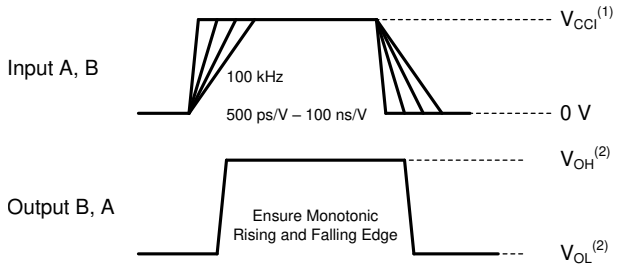
表 7-1. Load Circuit Conditions

Parameter		V_{CCO}	R_L	C_L	S_1	V_{TP}
Δt/Δv	Input transition rise or fall rate	0.65 V – 3.6 V	1 MΩ	15 pF	Open	N/A
t_{pd}	Propagation (delay) time	1.1 V – 3.6 V	2 kΩ	15 pF	Open	N/A
		0.65 V – 0.95 V	20 kΩ	15 pF	Open	N/A
t_{en}, t_{dis}	Enable time, disable time	3 V – 3.6 V	2 kΩ	15 pF	2 × V_{CCO}	0.3 V
		1.65 V – 2.7 V	2 kΩ	15 pF	2 × V_{CCO}	0.15 V
		1.1 V – 1.6 V	2 kΩ	15 pF	2 × V_{CCO}	0.1 V
		0.65 V – 0.95 V	20 kΩ	15 pF	2 × V_{CCO}	0.1 V
t_{en}, t_{dis}	Enable time, disable time	3 V – 3.6 V	2 kΩ	15 pF	GND	0.3 V
		1.65 V – 2.7 V	2 kΩ	15 pF	GND	0.15 V
		1.1 V – 1.6 V	2 kΩ	15 pF	GND	0.1 V
		0.65 V – 0.95 V	20 kΩ	15 pF	GND	0.1 V



1. V_{CCI} is the supply pin associated with the input port.
2. V_{OH} and V_{OL} are typical output voltage levels that occur with specified R_L, C_L, and S_1

图 7-2. Propagation Delay



1. V_{CCI} is the supply pin associated with the input port.
2. V_{OH} and V_{OL} are typical output voltage levels that occur with specified R_L, C_L, and S_1

图 7-3. Input Transition Rise or Fall Rate

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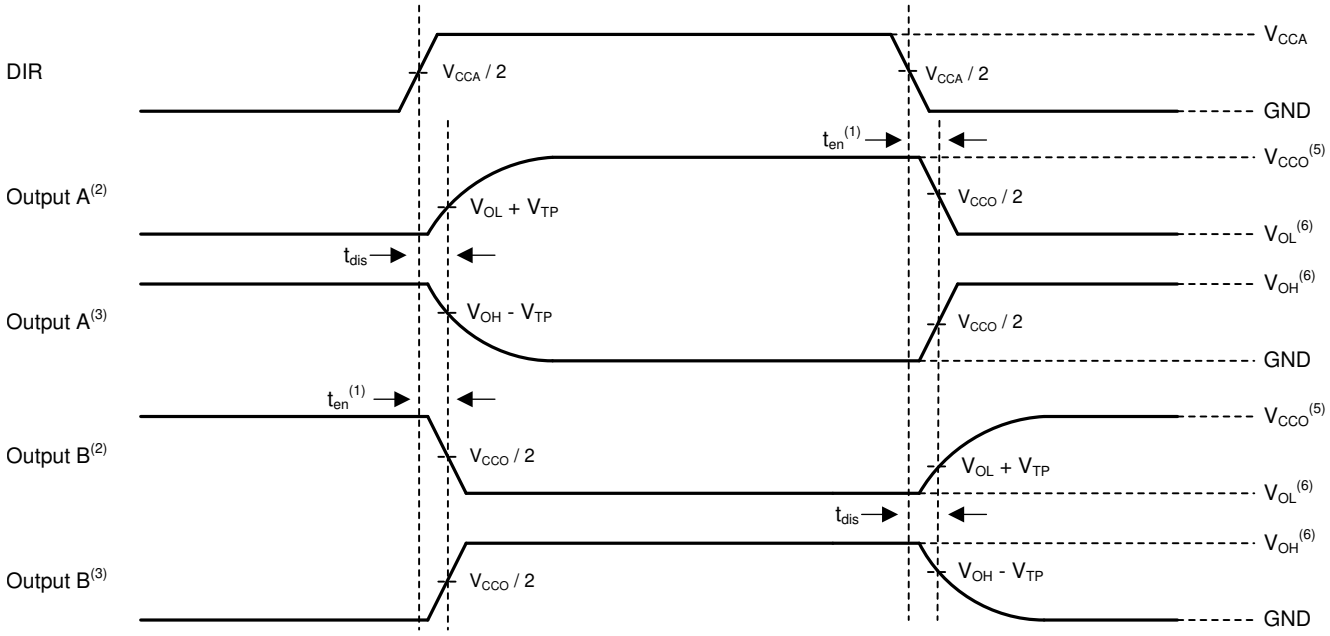

1. Illustrative purposes only. Enable Time is a calculation as described in the data sheet.
2. Output waveform on the condition that input is driven to a valid Logic Low.
3. Output waveform on the condition that input is driven to a valid Logic High.
4. V_{CCI} is the supply pin associated with the input port
5. V_{CCO} is the supply pin associated with the output port.
6. V_{OH} and V_{OL} are typical output voltage levels that occur with specified R_L, C_L, and S_1

图 7-4. Disable and Enable Time

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8 Detailed Description

8.1 Overview

The SN74AXCH1T45 is single-bit, dual-supply, noninverting voltage level translator. Pin A and the direction control pin are referenced to V_{CCA} logic levels and pin B is referenced to V_{CCB} logic levels, as depicted in . The A port can accept I/O voltages ranging from 0.65 V to 3.6 V, and the B port can accept I/O voltages from 0.65 V to 3.6 V. A logic high on the DIR pin enables data transmission from A to B and a logic low on the DIR pin enables data transmission from B to A.

8.2 Functional Block Diagram

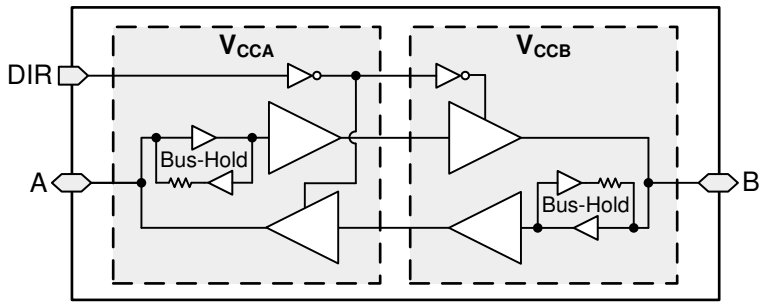

图 8-1. Functional Block Diagram

8.3 Feature Description

8.3.1 Standard CMOS Inputs

Standard CMOS inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics*, using ohm's law (R = V ÷ I).

Signals applied to the inputs need to have fast edge rates, as defined by $\Delta t/\Delta v$ in *Recommended Operating Conditions* to avoid excessive current consumption and oscillations. If a slow or noisy input signal is required, a device with a Schmitt-trigger input should be used to condition the input signal prior to the standard CMOS input.

8.3.2 Balanced High-Drive CMOS Push-Pull Outputs

A balanced output allows the device to sink and source similar currents. The high drive capability of this device creates fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

8.3.3 Partial Power Down (I_{off})

The inputs and outputs for this device enter a high-impedance state when the device is powered down, inhibiting current backflow into the device. The maximum leakage into or out of any input or output pin on the device is specified by I_{off} in the *Electrical Characteristics*.

8.3.4 V_{CC} Isolation

The inputs and outputs for this device enter a high-impedance state when either supply is <100mV.

8.3.5 Over-voltage Tolerant Inputs

Input signals to this device can be driven above the supply voltage so long as they remain below the maximum input voltage value specified in the *Recommended Operating Conditions*.

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8.3.6 Negative Clamping Diodes

The inputs and outputs to this device have negative clamping diodes as depicted in 图 8-2.

CAUTION

Voltages beyond the values specified in the Absolute Maximum Ratings table can cause damage to the device. The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

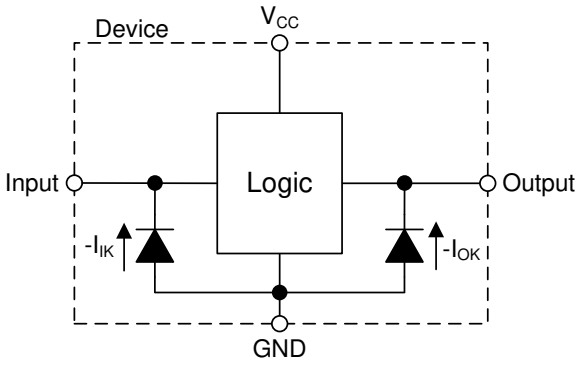

图 8-2. Electrical Placement of Clamping Diodes for Each Input and Output

8.3.7 Fully Configurable Dual-Rail Design

Both the V_{CCA} and V_{CCB} pins can be supplied at any voltage from 0.65 V to 3.6 V, making the device suitable for translating between any of the voltage nodes (0.7 V, 0.8 V, 0.9 V, 1.2 V, 1.8 V, 2.5 V and 3.3 V).

8.3.8 Supports High-Speed Translation

The SN74AXCH1T45 device can support high data-rate applications. The translated signal data rate can be up to 500 Mbps when the signal is translated from 1.8 V to 3.3 V.

8.3.9 Bus-Hold Data Inputs

Each data input on this device includes a weak latch that maintains a valid logic level on the input. The state of these latches is unknown at startup and remains unknown until the input has been forced to a valid high or low state. After data has been sent through a channel, the latch then maintains the previous state on the input if the line is left floating. It is not recommended to use pull-up or pull-down resistors together with a bus-hold input, as it may cause undefined inputs to occur which leads to excessive current consumption.

Bus-hold data inputs prevent floating inputs on this device. The *Implications of Slow or Floating CMOS Inputs* application report explains the problems associated with leaving CMOS inputs floating.

These latches remain active at all times, independent of all control signals such as direction control or output enable.

The *Bus-Hold Circuit* application report has additional details regarding bus-hold inputs.

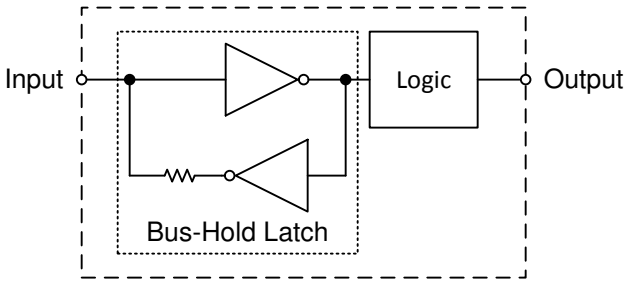

图 8-3. Simplified Schematic For Device With Bus-Hold Data Inputs

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8.4 Device Functional Modes

表 8-1 lists the device functions for the DIR input.

表 8-1. Function Table

INPUT(1) DIR	OPERATION
L	B data to A bus
H	A data to B bus

(1) Input circuits of the data I/Os always are active.

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9 Application and Implementation

Note

以下应用部分的信息不属于 TI 组件规范，TI 不担保其准确性和完整性。客户应负责确定 TI 组件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

9.1 Application Information

The SN74AXCH1T45 device can be used in level-translation applications for interfacing devices or systems with one another when they are operating at different interface voltages. The maximum data rate can be up to 500 Mbps when the device translate signals from 1.8 V to 3.3 V.

9.1.1 Enable Times

Calculate the enable times for the SN74AXC1T45 using the following formulas:

$$t_{A_en}\ (\text{DIR to A}) = t_{dis}\ (\text{DIR to B}) + t_{pd}\ (\text{B to A}) \quad (1)$$

$$t_{B_en}\ (\text{DIR to B}) = t_{dis}\ (\text{DIR to A}) + t_{pd}\ (\text{A to B}) \quad (2)$$

In a bidirectional application, these enable times provide the maximum delay time from the time the DIR bit is switched until an output is expected. For example, if the SN74AXCH1T45 initially is transmitting from A to B, then the DIR bit is switched; the B port of the device must be disabled (t_{dis}) before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay (t_{pd}). To avoid bus contention care should be taken to not apply an input signal prior to the output port being disabled (t_{dis} max).

9.2 Typical Applications

9.2.1 Interrupt Request Application

图 9-1 shows an example of the SN74AXCH1T45 being used in an application where a system controller flags an interrupt request (IRQ) to the CPU. The system controller determines the direction of the IRQ line to either flag an interrupt to the CPU or allow the CPU to drive data on the line. In this application the controller is operating at 3.3 V while the CPU can be operating as low as 0.65 V.

The SN74AXCH1T45 device is used to ensure that these devices can communicate at the appropriate voltage levels. Because the SN74AXCH1T45 does not have an output-enable ($\overline{OE}$) pin, the system designer should take precautions to avoid bus contention between the CPU and controller when changing directions.

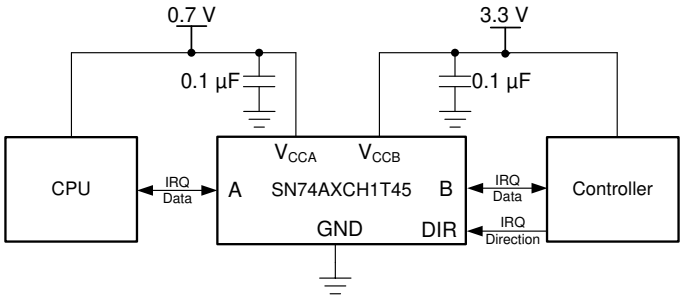

图 9-1. Interrupt Request Application

9.2.1.1 Design Requirements

For this design example, use the parameters listed in 表 9-1.

表 9-1. Design Parameters

DESIGN PARAMETERS	EXAMPLE VALUES
Input voltage range	0.65 V to 3.6 V

表 9-1. Design Parameters (continued)

DESIGN PARAMETERS	EXAMPLE VALUES
Output voltage range	0.65 V to 3.6 V

9.2.1.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
  - Use the supply voltage of the device that is driving the SN74AXCH1T45 device to determine the input voltage range. For a valid logic-high, the value must exceed the high-level input voltage (V_{IH}) of the input port. For a valid logic low the value must be less than the low-level input voltage (V_{IL}) of the input port.
- Output voltage range
  - Use the supply voltage of the device that the SN74AXCH1T45 device is driving to determine the output voltage range.

9.2.1.3 Application Curve

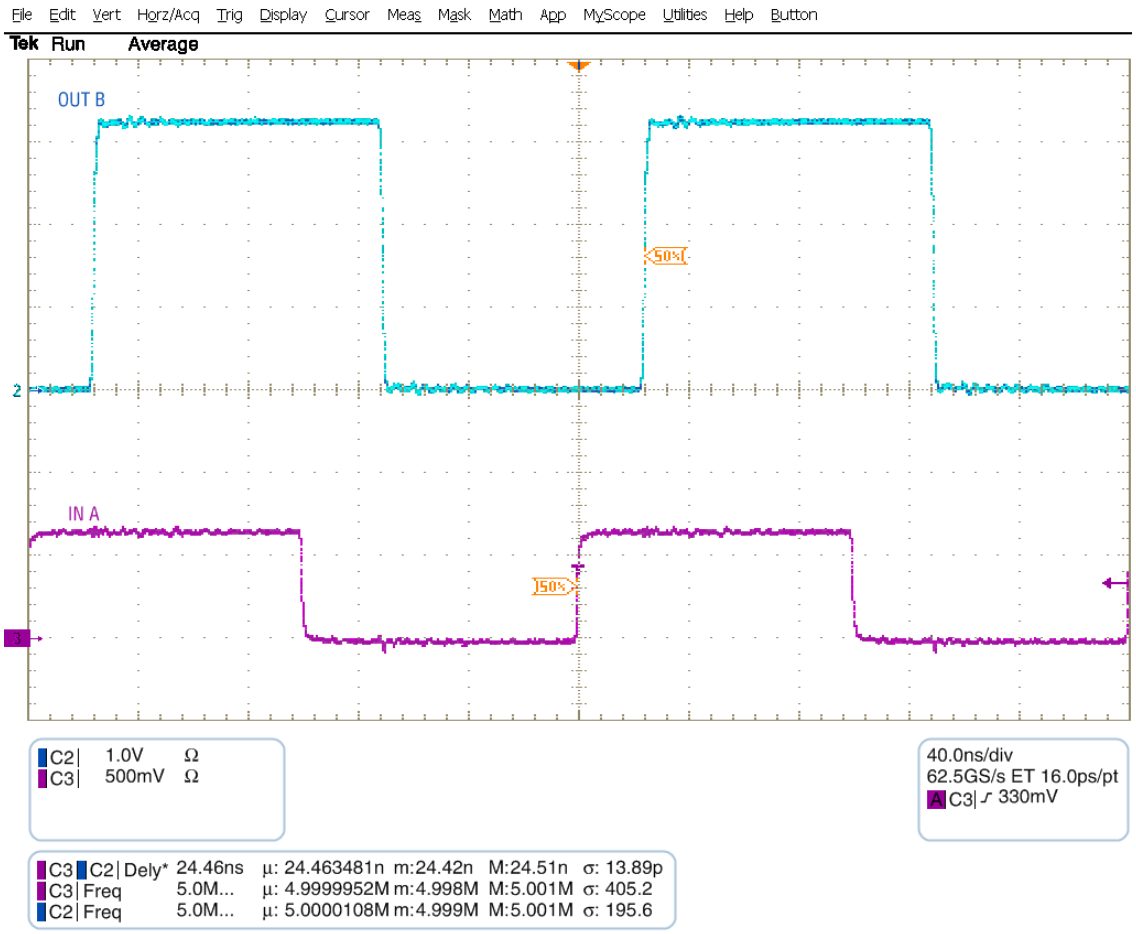

图 9-2. Up Translation at 2.5 MHz (0.7 V to 3.3 V)

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9.2.2 Universal Asynchronous Receiver-Transmitter (UART) Interface Application

图 9-3 shows the SN74AXCH1T45 being used for the two-bit UART interface application. One SN74AXCH1T45 device is used to level shift the voltage and drive the TX from the processor to the GPS Module while a second SN74AXCH1T45 device is used to drive the TX Data line from the GPS Module to the Processor. Devices with bus-hold inputs remove the requirement for external pullup resistors to maintain a valid logic level at the input.

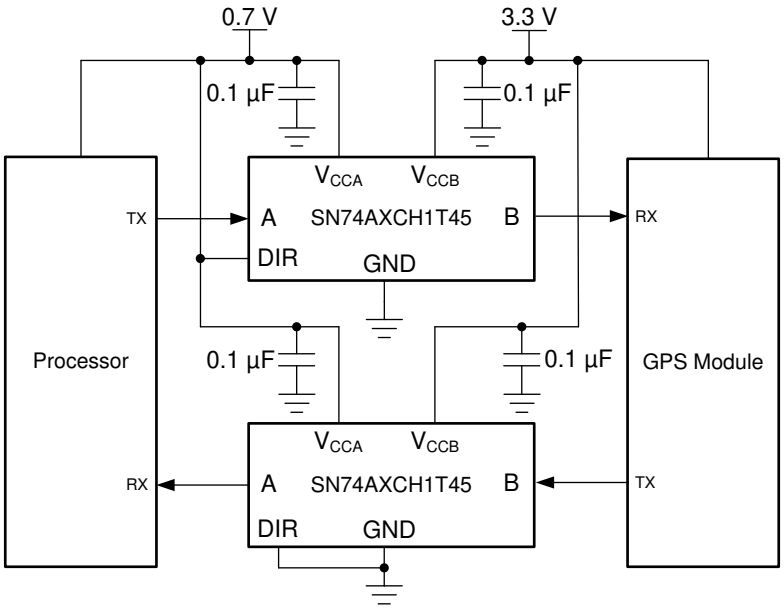

图 9-3. UART Interface Application

9.2.2.1 Design Requirements

Refer to *Design Requirements*.

9.2.2.2 Detailed Design Procedure

Refer to *Detailed Design Procedure*.

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10 Power Supply Recommendations

Always apply a ground reference to the GND pins first. This device is designed for glitch free power sequencing without any supply sequencing requirements such as ramp order or ramp rate.

This device was designed with various power supply sequencing methods in mind to help prevent unintended triggering of downstream devices. For more information regarding the power up glitch performance of the AXC family of level translators, see the *Power Sequencing for AXC Family of Devices* application report

11 Layout

11.1 Layout Guidelines

To ensure reliability of the device, following common printed-circuit board layout guidelines are recommended:

- Use bypass capacitors on the power supply pins and place them as close to the device as possible.
- Use short trace lengths to avoid excessive loading.

11.2 Layout Example

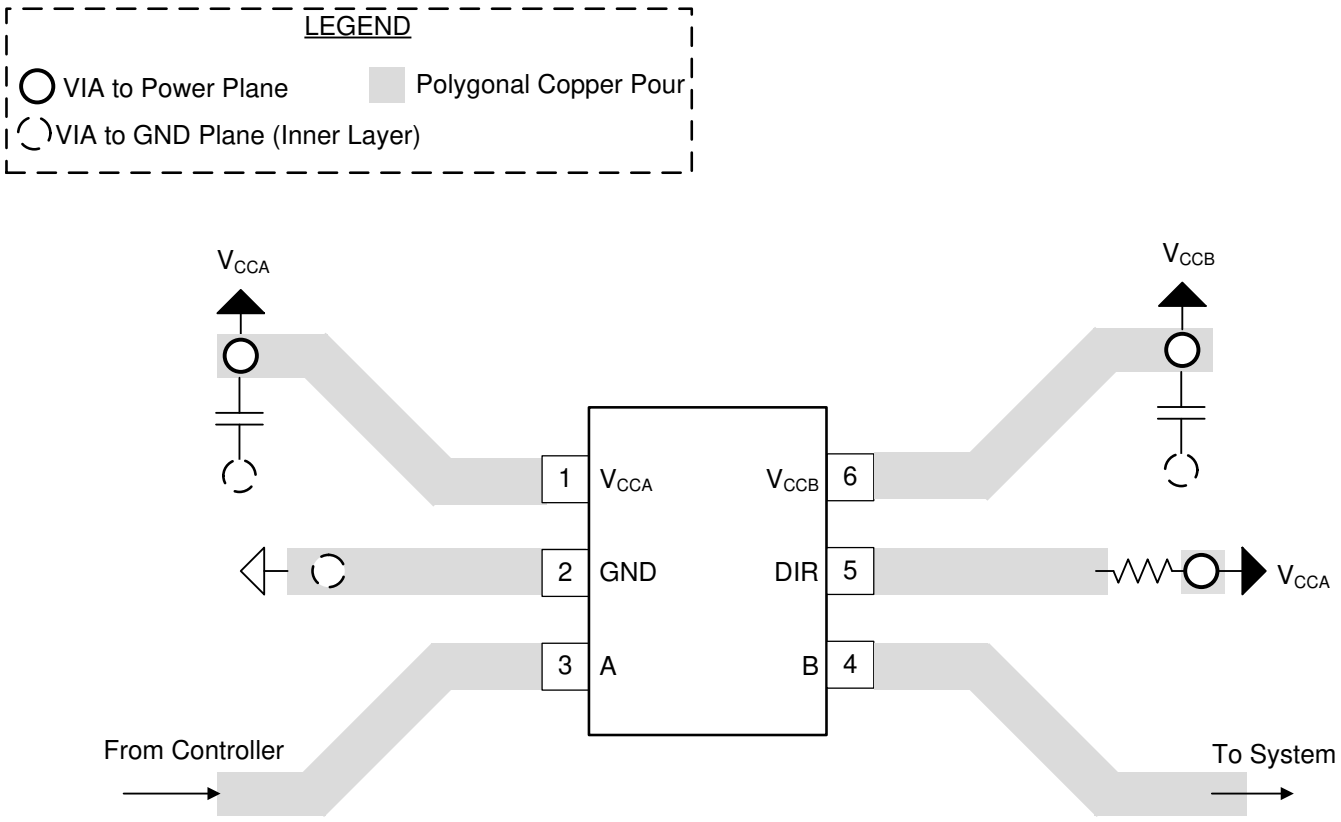

图 11-1. PCB Layout Example

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12 Device and Documentation Support

12.1 Documentation Support

For related documentation see the following:

- Texas Instruments, *Evaluate SN74AXC1T45DRL Using a Generic EVM* application report
- Texas Instruments, *System Considerations For Using Bus-hold Circuits To Avoid Floating Inputs*application report
- Texas Instruments, *Power Sequencing for the AXC Family of Devices* application report
- Texas Instruments, *Implications of Slow or Floating CMOS Inputs* application report

12.2 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击*订阅更新* 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

12.3 支持资源

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链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的使用条款。

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ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

12.6 术语表

TI 术语表　　本术语表列出并解释了术语、首字母缩略词和定义。

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74AXCH1T45DBVR	Active	Production	SOT-23 (DBV) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1PNL
SN74AXCH1T45DBVR.B	Active	Production	SOT-23 (DBV) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1PNL
SN74AXCH1T45DBVRG4	Active	Production	SOT-23 (DBV) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1PNL
SN74AXCH1T45DBVRG4.B	Active	Production	SOT-23 (DBV) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1PNL
SN74AXCH1T45DCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1CC
SN74AXCH1T45DCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1CC
SN74AXCH1T45DRY2	Active	Production	SON (DRY) | 6	5000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	IR
SN74AXCH1T45DRY2.B	Active	Production	SON (DRY) | 6	5000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	IR
SN74AXCH1T45DRYR	Active	Production	SON (DRY) | 6	5000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	II
SN74AXCH1T45DRYR.B	Active	Production	SON (DRY) | 6	5000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	II
SN74AXCH1T45DTQR	Active	Production	X2SON (DTQ) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DM
SN74AXCH1T45DTQR.B	Active	Production	X2SON (DTQ) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DM

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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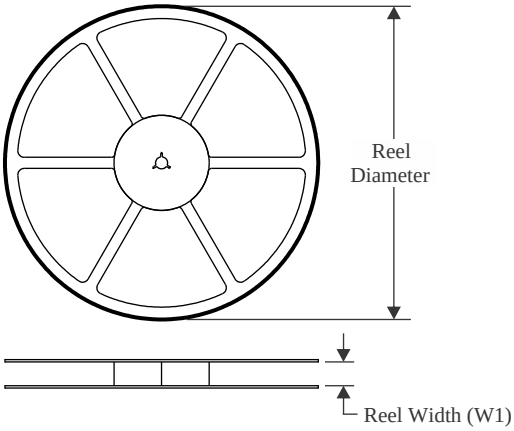
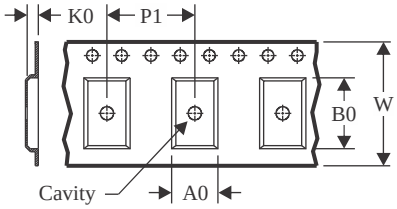
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

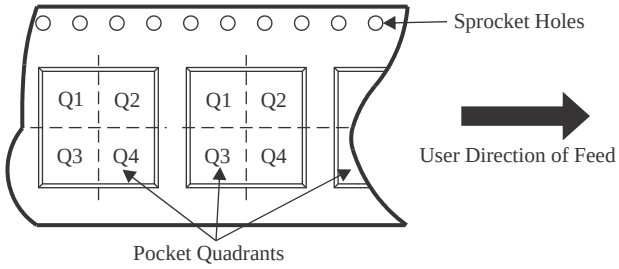


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

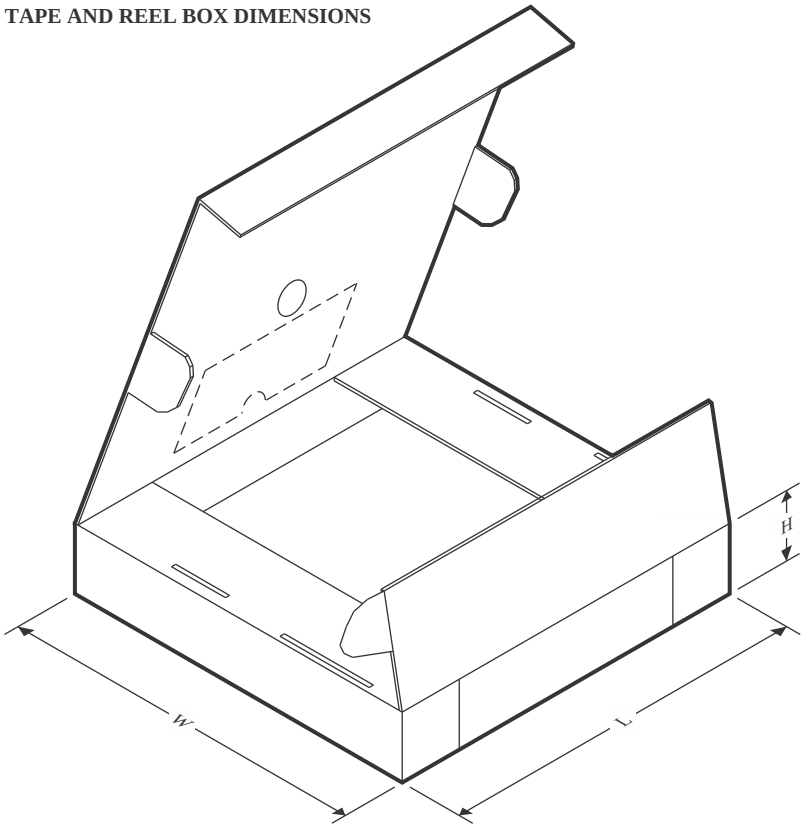
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AXCH1T45DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74AXCH1T45DBVRG4	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74AXCH1T45DCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.55	1.2	4.0	8.0	Q3
SN74AXCH1T45DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74AXCH1T45DRY2	SON	DRY	6	5000	180.0	9.5	1.6	1.15	0.68	4.0	8.0	Q3
SN74AXCH1T45DRY2	SON	DRY	6	5000	180.0	8.4	1.2	1.65	0.63	4.0	8.0	Q1
SN74AXCH1T45DRYR	SON	DRY	6	5000	180.0	8.4	1.2	1.65	0.63	4.0	8.0	Q1
SN74AXCH1T45DRYR	SON	DRY	6	5000	180.0	9.5	1.2	1.65	0.7	4.0	8.0	Q1
SN74AXCH1T45DTQR	X2SON	DTQ	6	3000	180.0	9.5	0.94	1.13	0.5	2.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

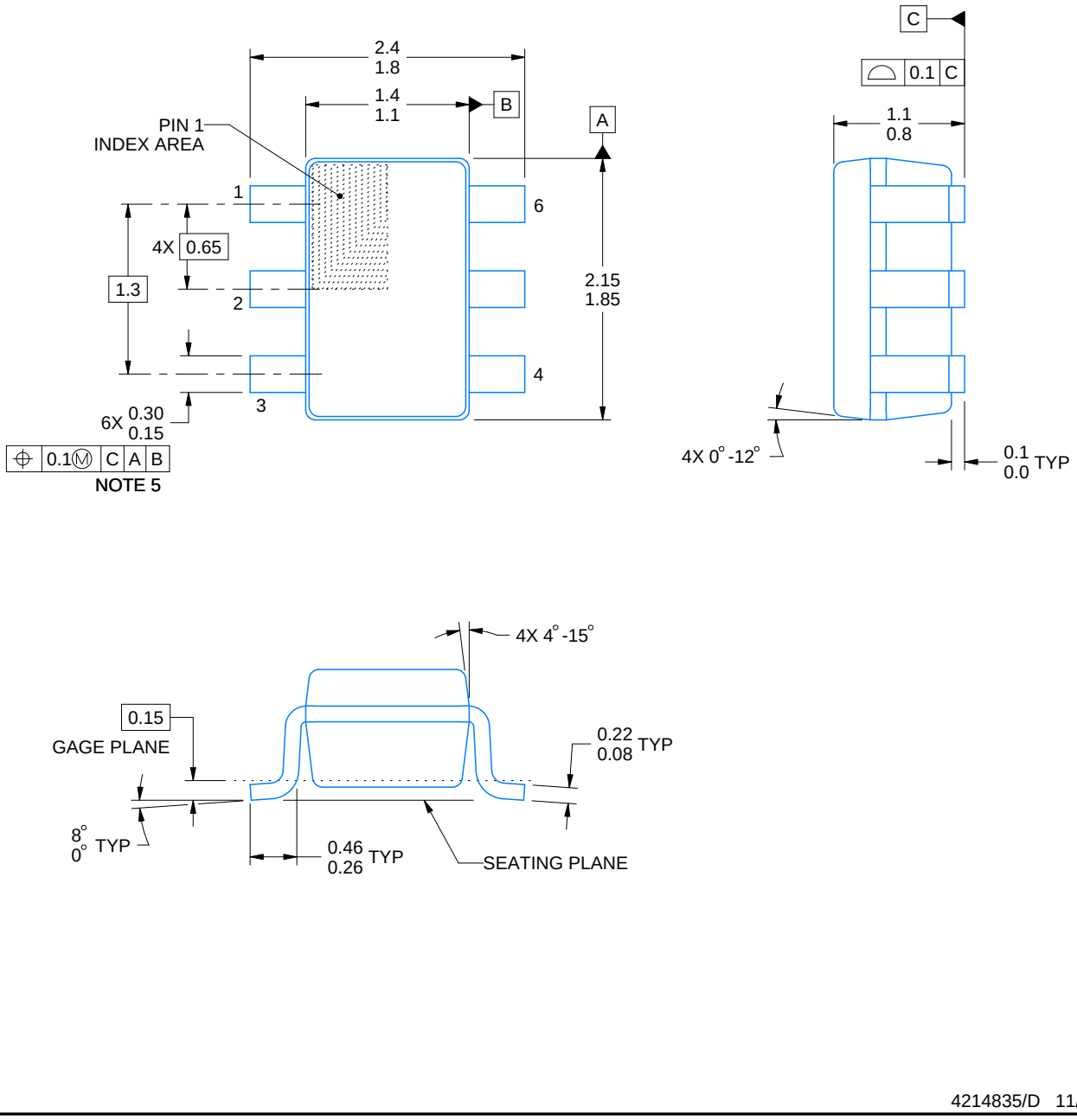
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AXCH1T45DBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
SN74AXCH1T45DBVRG4	SOT-23	DBV	6	3000	210.0	185.0	35.0
SN74AXCH1T45DCKR	SC70	DCK	6	3000	210.0	185.0	35.0
SN74AXCH1T45DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
SN74AXCH1T45DRY2	SON	DRY	6	5000	189.0	185.0	36.0
SN74AXCH1T45DRY2	SON	DRY	6	5000	210.0	185.0	35.0
SN74AXCH1T45DRYR	SON	DRY	6	5000	210.0	185.0	35.0
SN74AXCH1T45DRYR	SON	DRY	6	5000	189.0	185.0	36.0
SN74AXCH1T45DTQR	X2SON	DTQ	6	3000	189.0	185.0	36.0

PACKAGE OUTLINE

DCK0006A

SOT - 1.1 max height

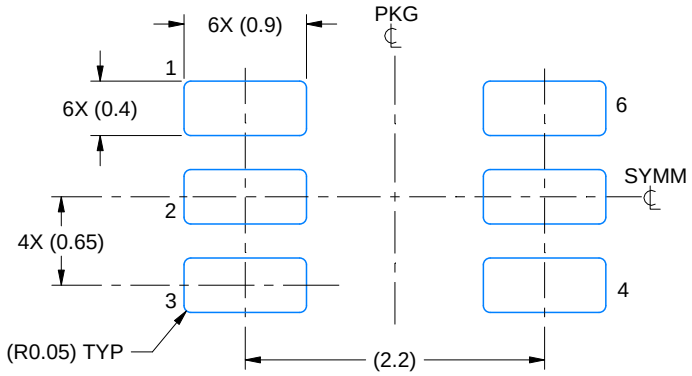
SMALL OUTLINE TRANSISTOR



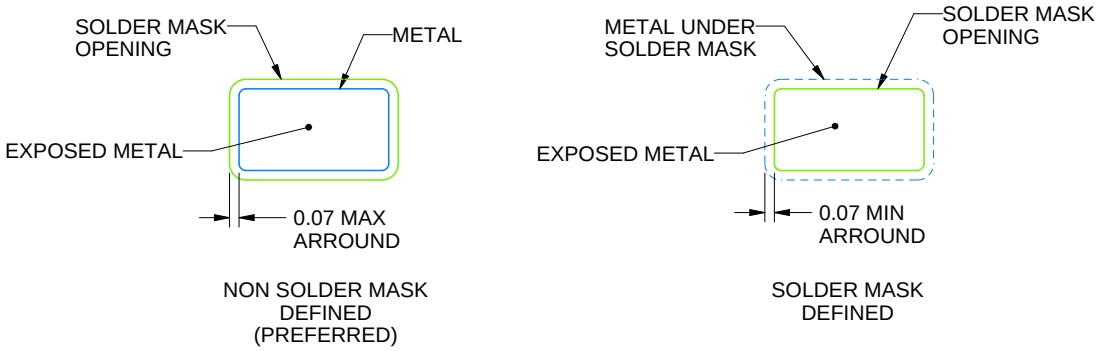
4214835/D 11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
4. Falls within JEDEC MO-203 variation AB.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X

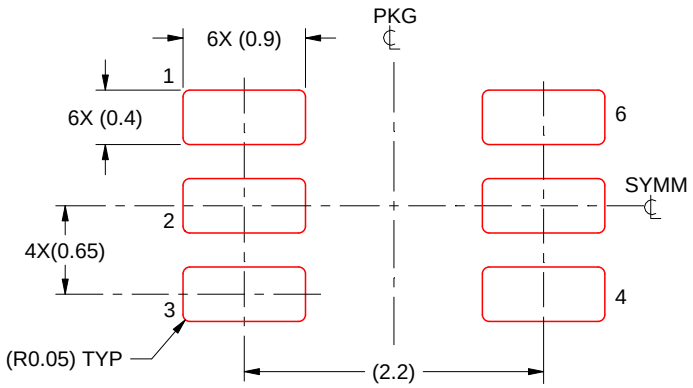


SOLDER MASK DETAILS

4214835/D 11/2024

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214835/D 11/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

DRY 6 USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

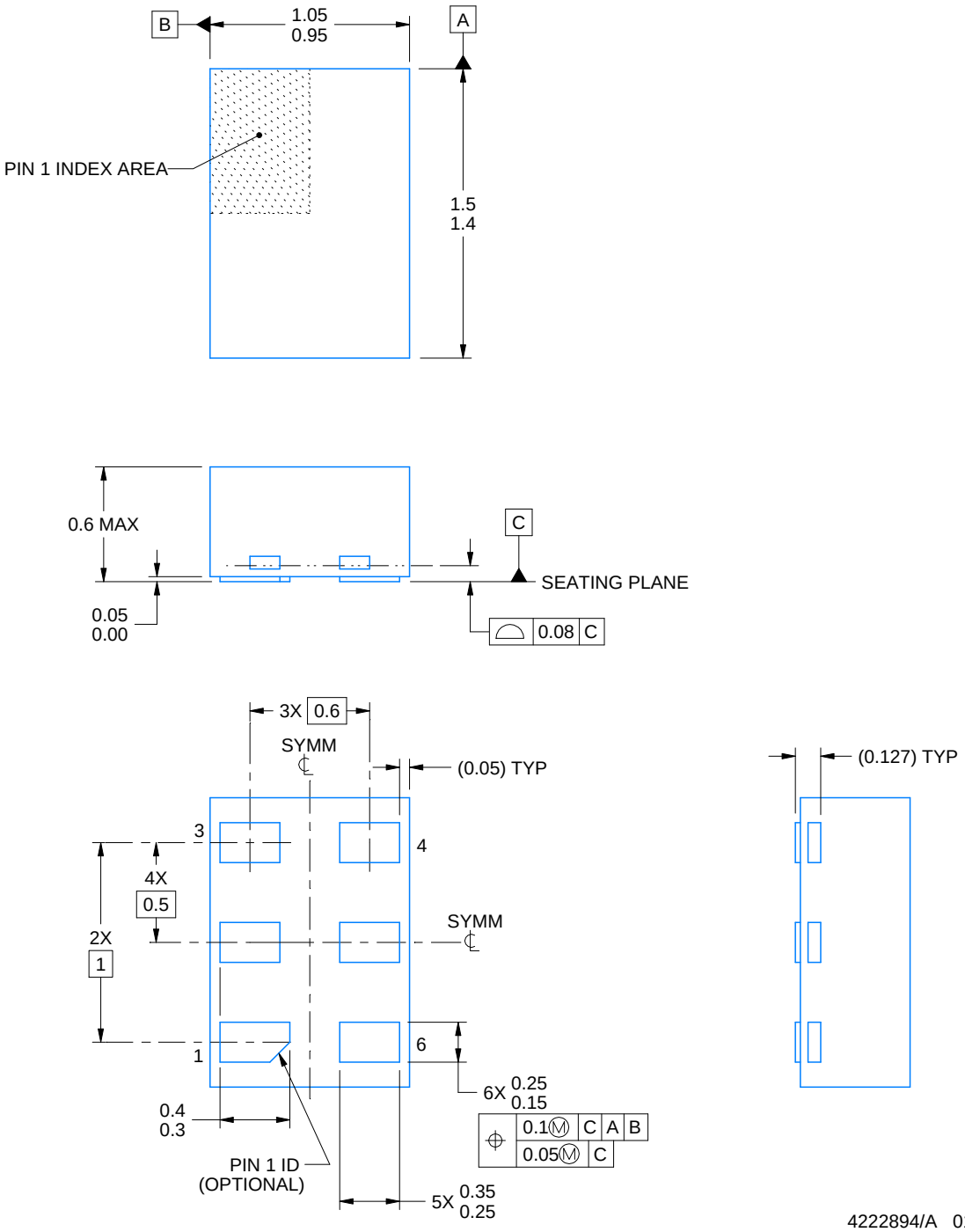
Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

PACKAGE OUTLINE

DRY0006A

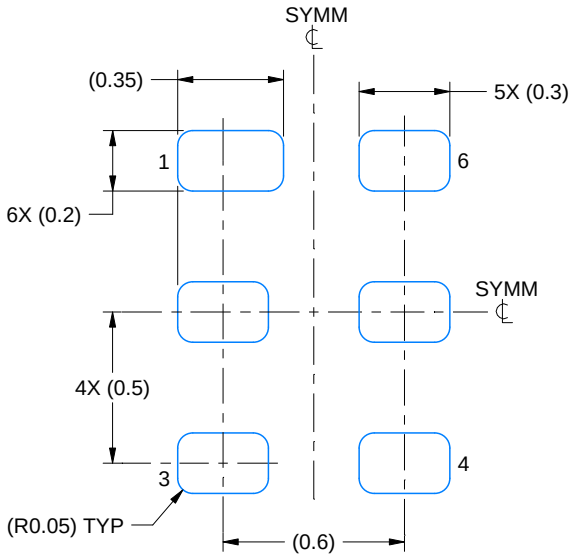
USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

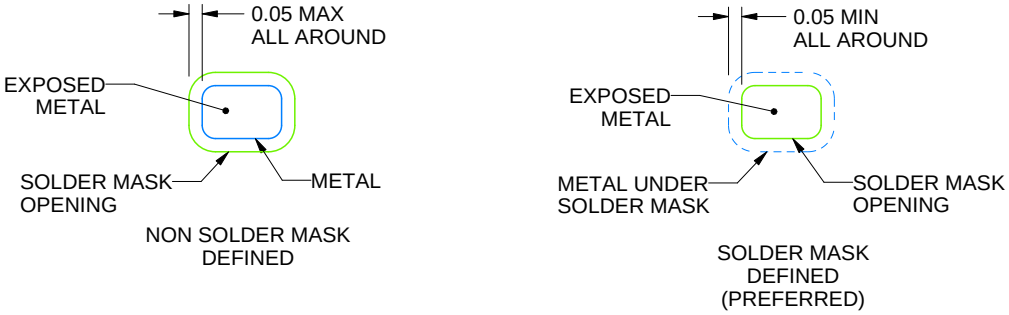


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.



LAND PATTERN EXAMPLE
1:1 RATIO WITH PKG SOLDER PADS
EXPOSED METAL SHOWN
SCALE:40X



SOLDER MASK DETAILS

4222894/A 01/2018

NOTES: (continued)

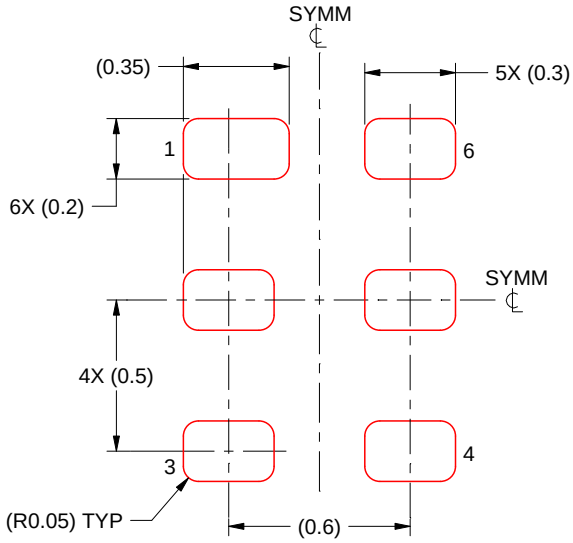
3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).

EXAMPLE STENCIL DESIGN

DRY0006A

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.075 - 0.1 mm THICK STENCIL
SCALE:40X

4222894/A 01/2018

NOTES: (continued)

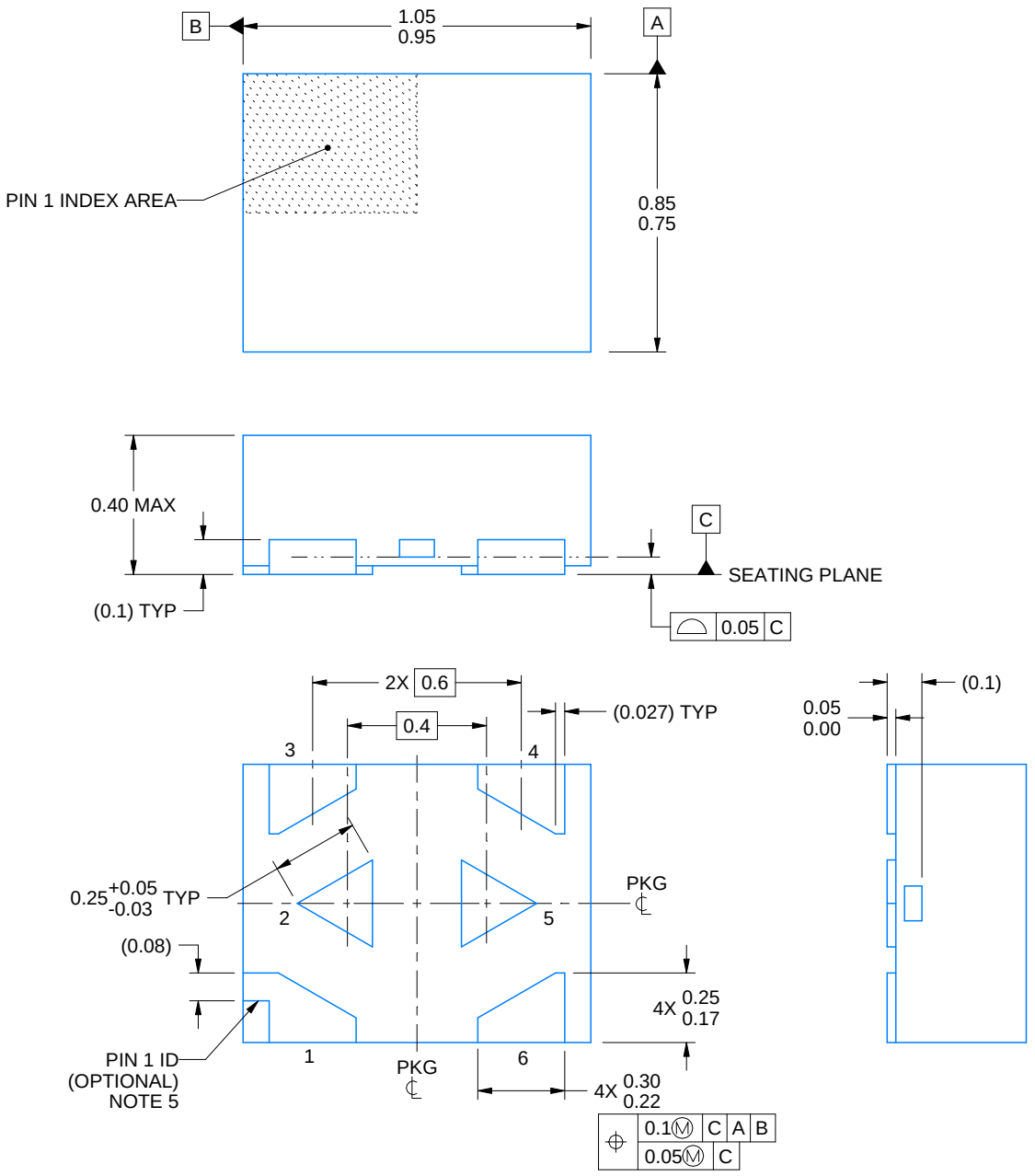
4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

DTQ0006A

PACKAGE OUTLINE

X2SON - 0.4 mm max height

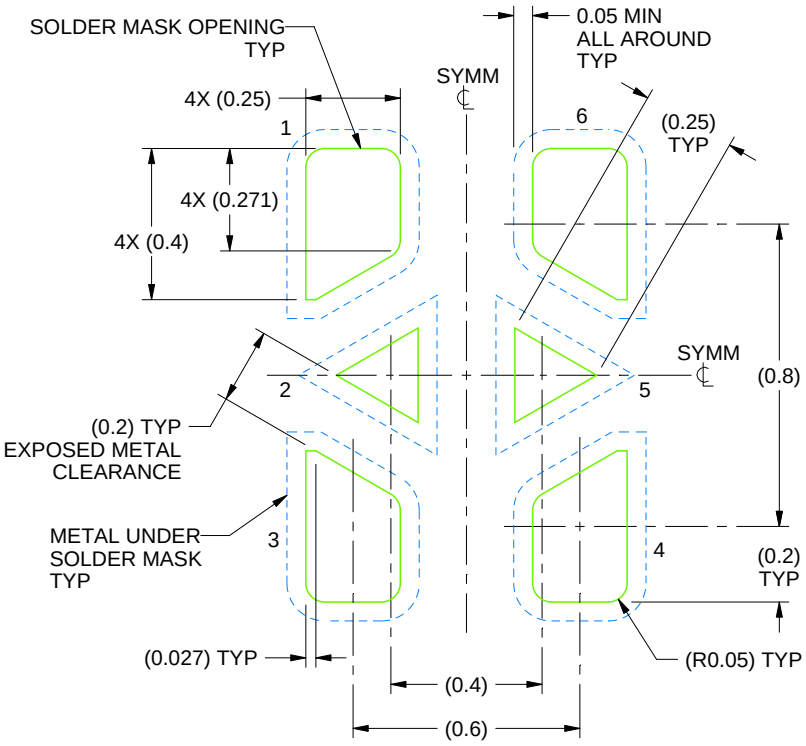
PLASTIC SMALL OUTLINE - NO LEAD



4224056/B 07/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pads must be soldered to the printed circuit board for optimal thermal and mechanical performance.
4. The size and shape of this feature may vary.
5. Features may not exist. Recommend use of pin 1 marking on top of package for orientation purposes.

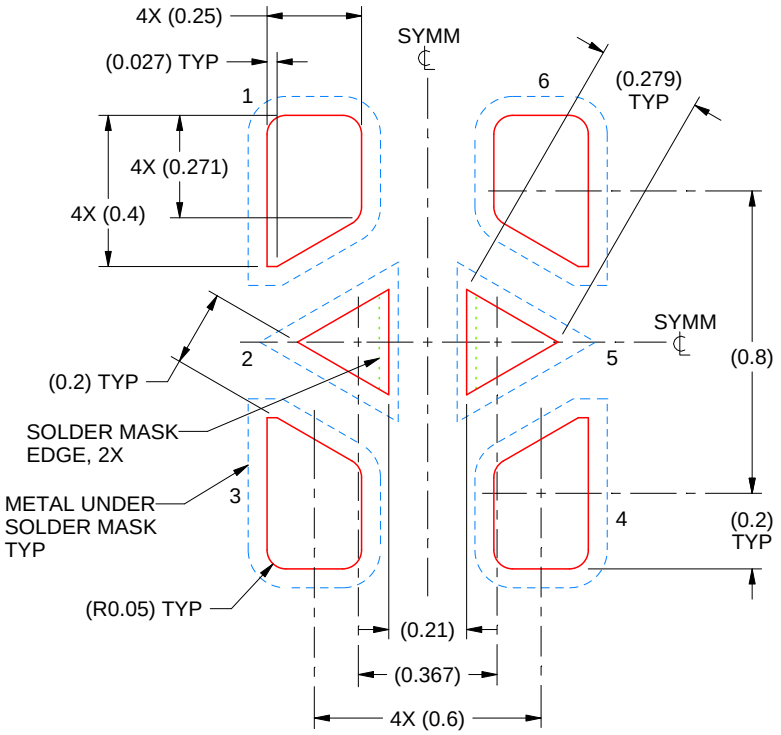


LAND PATTERN EXAMPLE
SOLDER MASK DEFINED
SCALE:50X

4224056/B 07/2024

NOTES: (continued)

6. This package is designed to be soldered to a thermal pads on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
7. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.



SOLDER PASTE EXAMPLE
BASED ON 0.07 mm THICK STENCIL

PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:50X

4224056/B 07/2024

NOTES: (continued)

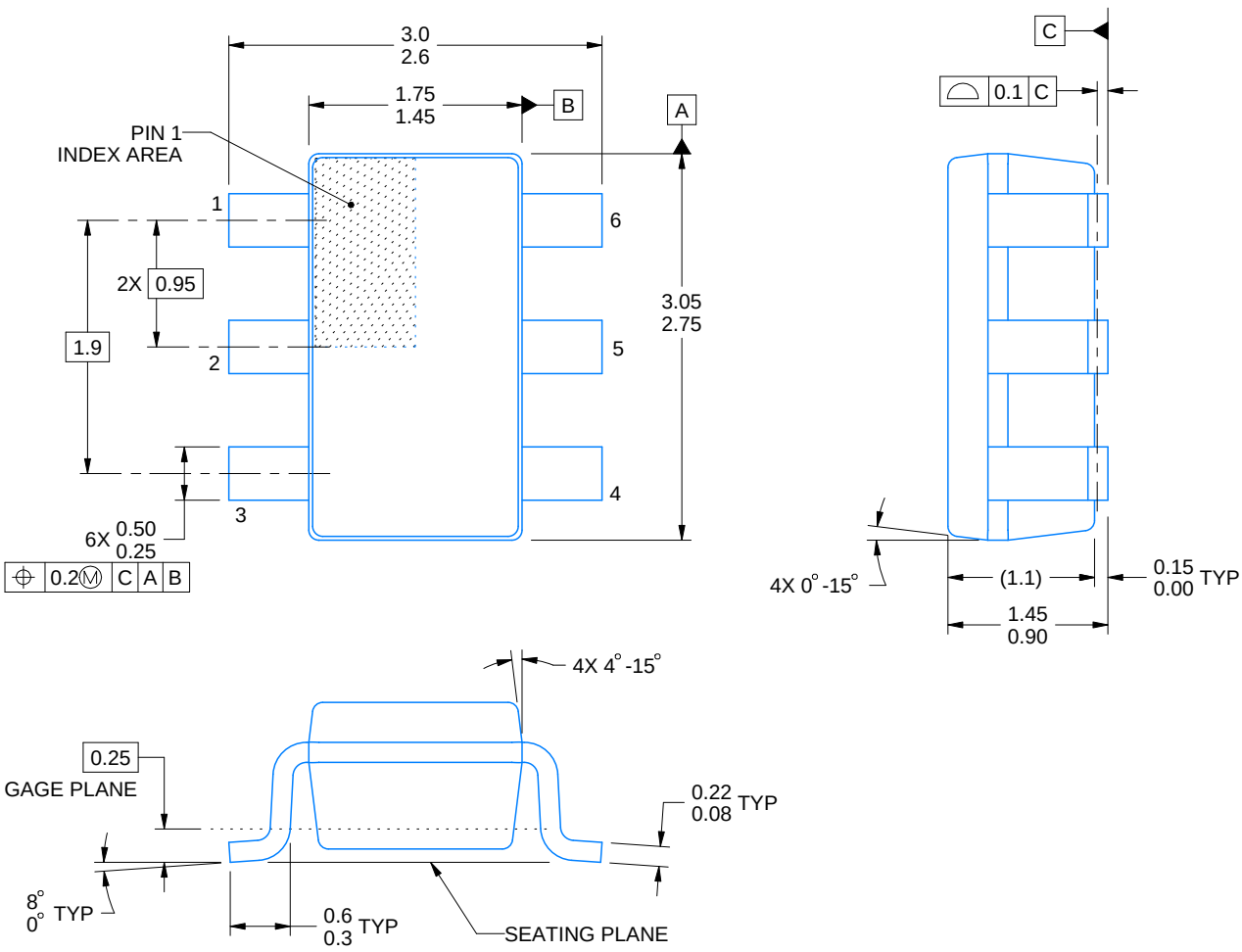
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

PACKAGE OUTLINE

DBV0006A

SOT-23 - 1.45 mm max height

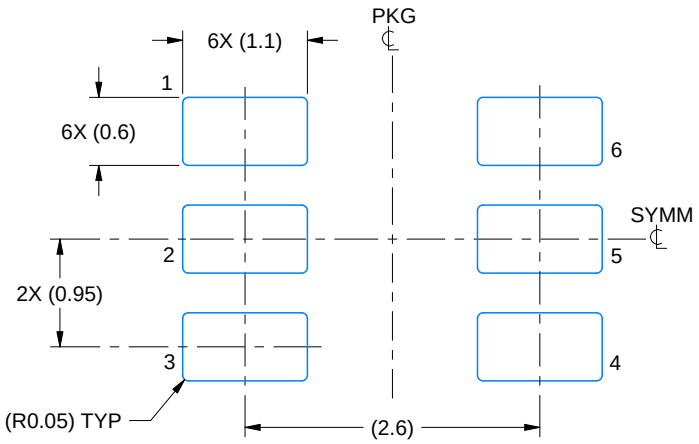
SMALL OUTLINE TRANSISTOR



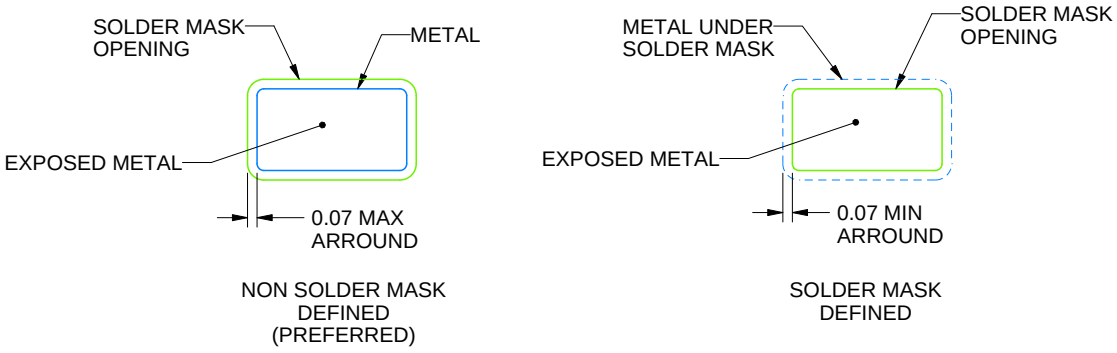
4214840/G 08/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Refernce JEDEC MO-178.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

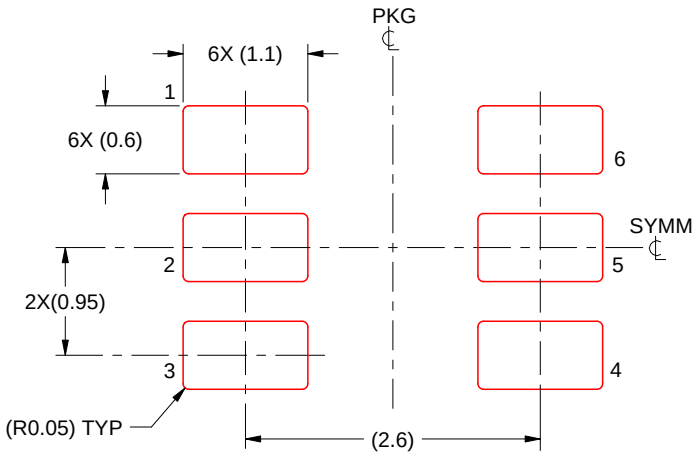


SOLDER MASK DETAILS

4214840/G 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214840/G 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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最后更新日期：2025 年 10 月